KA1M0680B/KA1M0680RB/ KA1H0680B/KA1H0680RFB

## Fairchild Power Switch(FPS)

Features

- Precision fixed operating frequency
- KA1M0680B,KA1M0680RB (67KHz)
- KA1H0680B,KA1H0680RFB (100KHz)
- Pulse by pulse over current limiting
- Over load protection
- Over voltage protection (Min. 23V)
- Internal thermal shutdown function
- Under voltage lockout
- Internal high voltage sense FET
- Latch up mode (KA1M0680B,KA1H0680B)
- Auto restart (KA1M0680RB,KA1H0680RFB)
- Soft start

Description

The Fairchild Power Switch(FPS) product family is specially designed for an off-line SMPS with minimal external components. The Fairchild Power Switch(FPS) consist of high voltage power SenseFET and current mode PWM controller IC. PWM controller features integrated fixed oscillator, under voltage lock out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, temperature compensated precision current sources for loop compensation and fault protection circuit. compared to discrete MOSFET and controller or R_{CC} switching converter solution, a Fairchild Power Switch(FPS) can reduce total component count, design size, weight and at the same time increase & efficiency, productivity, and system reliability. It has a basic platform well suited for cost effective design in either a flyback converter or a forward converter.

TO-3P-5L   **TO-3PF-5L**

1.DRAIN 2.GND 3.V_{CC} 4.FB 5.Soft Start
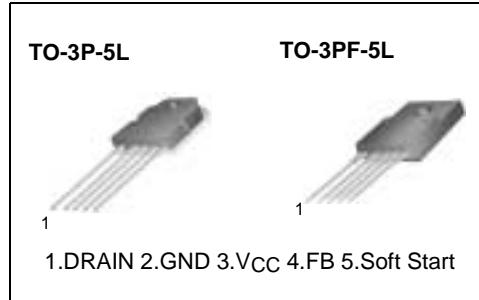
Internal Block Diagram

Rev.1.0.2

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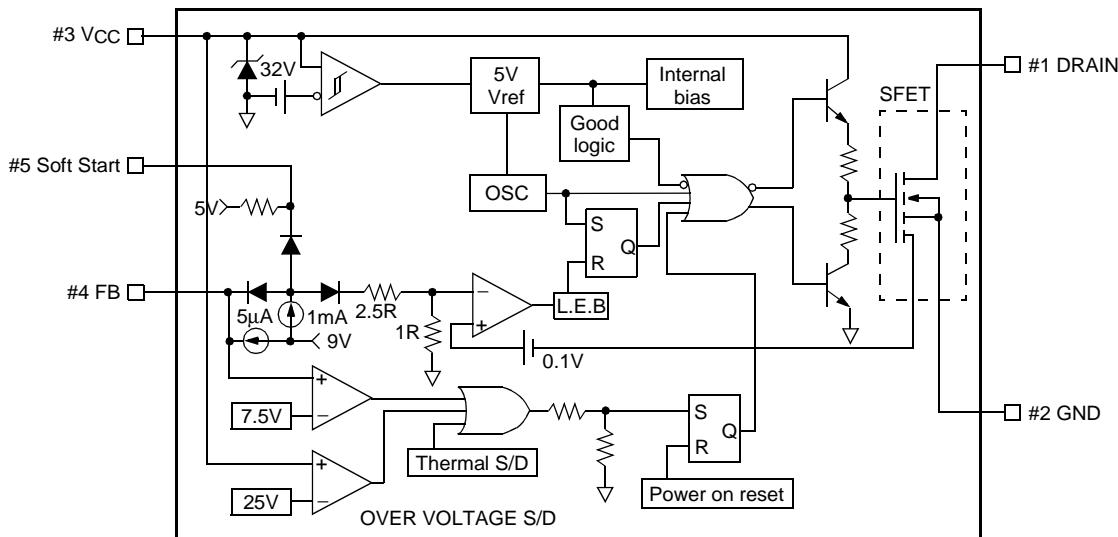
Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Maximum Drain voltage [1]	$V_{D,MAX}$	800	V
Drain Gate voltage (R_{GS}=1MΩ)	V_{DGR}	800	V
Gate source (GND) voltage	V_{GS}	±30	V
Drain current pulsed [2]	I_{DM}	24.0	A_{DC}
Single pulsed avalanche energy [3]	E_{AS}	455	mJ
Avalanche current [4]	I_{AS}	16	A
Continuous drain current (T_C=25°C)	I_D	6.0	A_{DC}
Continuous drain current (T_C=100°C)	I_D	4.0	A_{DC}
Maximum Supply voltage	$V_{CC,MAX}$	30	V
Input voltage range	V_{FB}	−0.3 to V_{SD}	V
Total power dissipation	P_D	150	W
	Derating	1.21	W/°C
Operating ambient temperature	T_A	−25 to +85	°C
Storage temperature	T_{STG}	−55 to +150	°C

Notes:

1. T_j=25°C to 150°C
2. Repetitive rating: Pulse width limited by maximum junction temperature
3. L=24mH, V_{DD}=50V, R_G=25Ω, starting T_j=25°C
4. L=13μH, starting T_j=25°C

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Electrical Characteristics (SFET part)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Drain source breakdown voltage	BV$_{DSS}$	V$_{GS}$=0V, I$_D$=50µA	800	-	-	V
Zero gate voltage drain current	I$_{DSS}$	V$_{DS}$=Max., Rating, V$_{GS}$=0V	-	-	50	µA
		V$_{DS}$=0.8Max., Rating, V$_{GS}$=0V, T$_C$=125°C	-	-	200	µA
Static drain source on resistance [note]	R$_{DS(ON)}$	V$_{GS}$=10V, I$_D$=4.0A	-	1.6	2.0	Ω
Forward transconductance [note]	gfs	V$_{DS}$=15V, I$_D$=4.0A	1.5	2.5	-	S
Input capacitance	Ciss	V$_{GS}$=0V, V$_{DS}$=25V, f=1MHz	-	1600	-	pF
Output capacitance	Coss		-	140	-	
Reverse transfer capacitance	Crss		-	42	-	
Turn on delay time	t$_{d(on)}$	V$_{DD}$=0.5BV$_{DSS}$, I$_D$=6.0A (MOSFET switching time are essentially independent of operating temperature)	-	60	-	nS
Rise time	tr		-	150	-	
Turn off delay time	t$_{d(off)}$		-	300	-	
Fall time	tf		-	130	-	
Total gate charge (gate-source+gate-drain)	Qg	V$_{GS}$=10V, I$_D$=6.0A, V$_{DS}$=0.5BV$_{DSS}$ (MOSFET switching time are essentially independent of operating temperature)	-	70	-	nC
Gate source charge	Qgs		-	16	-	
Gate drain (Miller) charge	Qgd		-	27	-	

Note:

Pulse test: Pulse width ≤ 300µS, duty cycle ≤ 2%

$S = \dfrac{1}{R}$

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Electrical Characteristics (CONTROL part)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
UVLO SECTION						
Start threshold voltage	V_{START}	-	14	15	16	V
Stop threshold voltage	V_{STOP}	After turn on	9	10	11	V
OSCILLATOR SECTION						
Initial accuracy	F_{OSC}	**KA1M0680B**	61	67	73	kHz
		KA1M0680RB	61	67	73	
		KA1H0680B	90	100	110	
		KA1H0680RFB	90	100	110	
Frequency change with temperature [2]	$\Delta F/\Delta T$	$-25°C \leq Ta \leq +85°C$	-	±5	±10	%
Maximum duty cycle	Dmax	**KA1M0680B**	74	77	80	%
		KA1M0680RB	74	77	80	
		KA1H0680B	64	67	70	
		KA1H0680RFB	64	67	70	
FEEDBACK SECTION						
Feedback source current	I_{FB}	Ta=25°C, $0V \leq Vfb \leq 3V$	0.7	0.9	1.1	mA
Shutdown Feedback voltage	V_{SD}	-	6.9	7.5	8.1	V
Shutdown delay current	Idelay	Ta=25°C, $5V \leq Vfb \leq V_{SD}$	4.0	5.0	6.0	μA
SOFT START SECTION						
Soft Start Voltage	V_{SS}	$V_{FB} = 2V$	4.7	5.0	5.3	V
Soft Start Current	I_{SS}	Sync & S/S=GND	0.8	1.0	1.2	mA
REFERENCE SECTION						
Output voltage [1]	Vref	Ta=25°C	4.80	5.00	5.20	V
Temperature Stability [1][2]	Vref/ΔT	$-25°C \leq Ta \leq +85°C$	-	0.3	0.6	mV/°C
CURRENT LIMIT (SELF-PROTECTION) SECTION						
Peak Current Limit	I_{OVER}	Max. inductor current	3.52	4.00	4.48	A
PROTECTION SECTION						
Thermal shutdown temperature (Tj) [1]	T_{SD}	-	140	160	-	°C
Over voltage protection voltage	V_{OVP}	-	23	25	28	V
TOTAL DEVICE SECTION						
Start Up current	I_{START}	V_{CC}=14V	0.1	0.3	0.45	mA
Operating supply current (control part only)	I_{OP}	Ta=25°C	6	12	18	mA
V_{CC} zener voltage	Vz	I_{CC}=20mA	30	32.5	35	V

Note:

1. These parameters, although guaranteed, are not 100% tested in production
2. These parameters, although guaranteed, are tested in EDS (wafer test) process

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Typical Performance Characteristics

(These characteristic graphs are normalized at Ta=25°C)
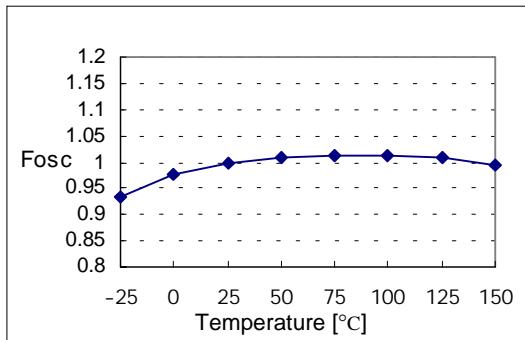
**Figure 1. Operating Frequency**
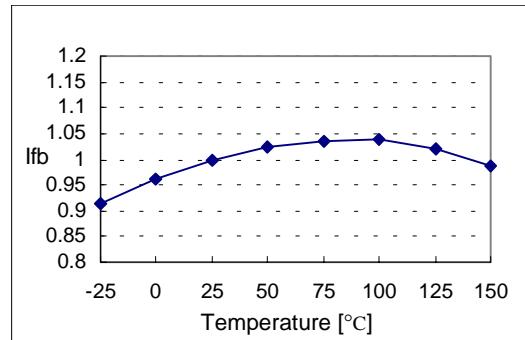
Figure 2. Feedback Source Current
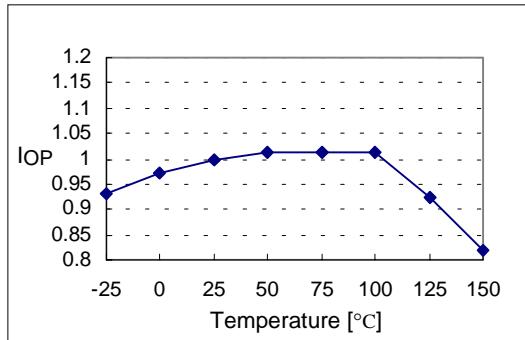
Figure 3. Operating Supply Current
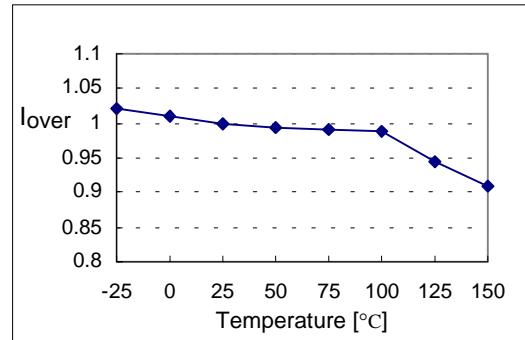
**Figure 4. Peak Current Limit**
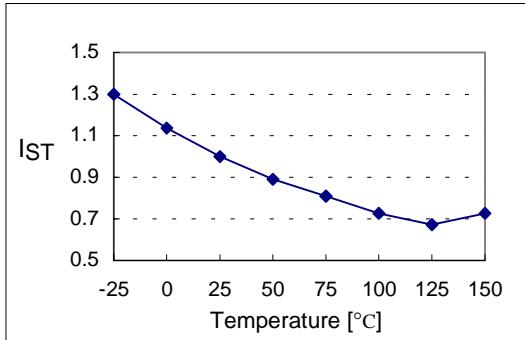
Figure 5. Start up Current
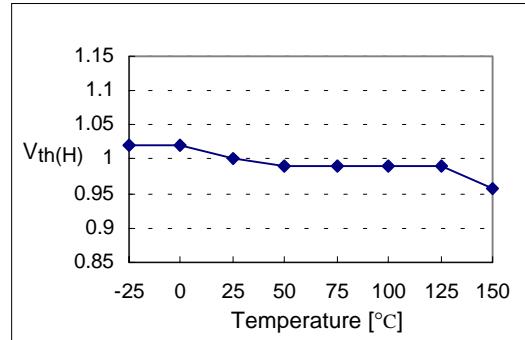
Figure 6. Start Threshold Voltage

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Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta=25°C)
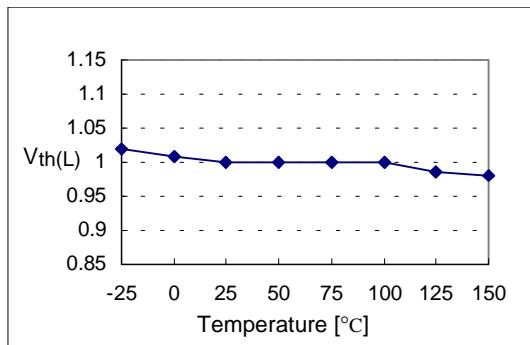
Figure 7. Stop Threshold Voltage
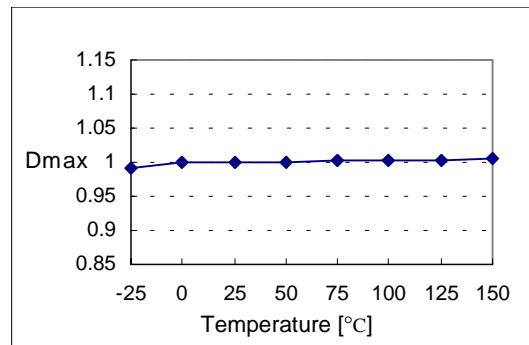
Figure 8. Maximum Duty Cycle
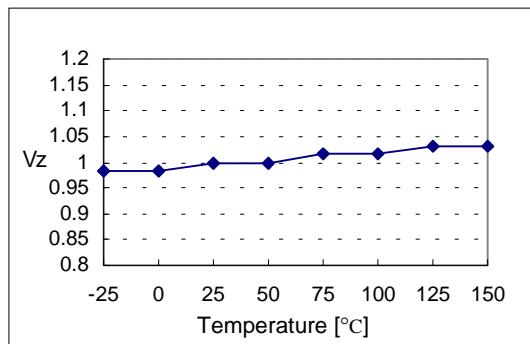
Figure 9. V$_{CC}$ Zener Voltage
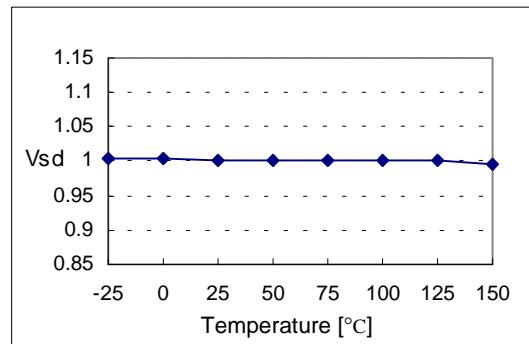
Figure 10. Shutdown Feedback Voltage
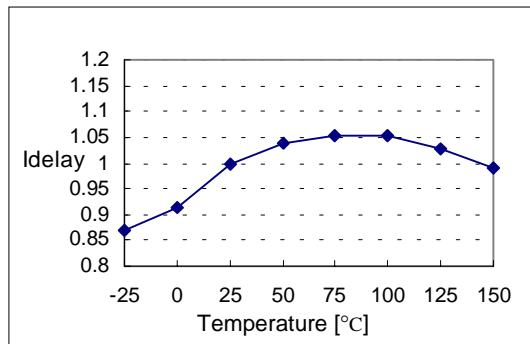
Figure 11. Shutdown Delay Current
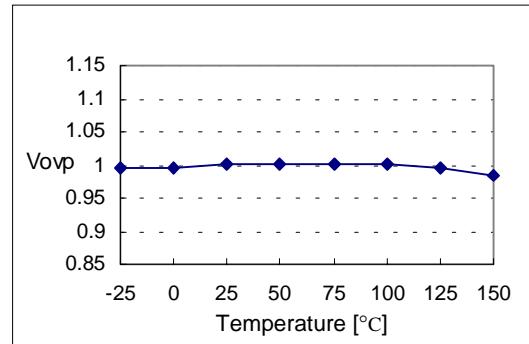
Figure 12. Over Voltage Protection

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Typical Performance Characteristics (Continued)

(These characteristic grahps are normalized at Ta=25°C)
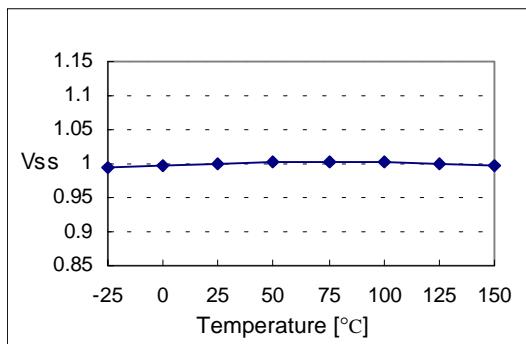
Figure 13. Soft Start Voltage
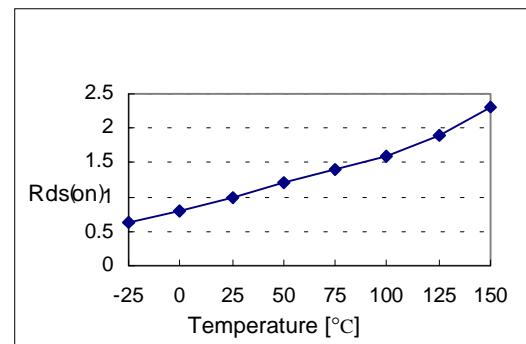
Figure 14. Static Drain-Source on Resistance

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Package Dimensions

TO-3P-5L
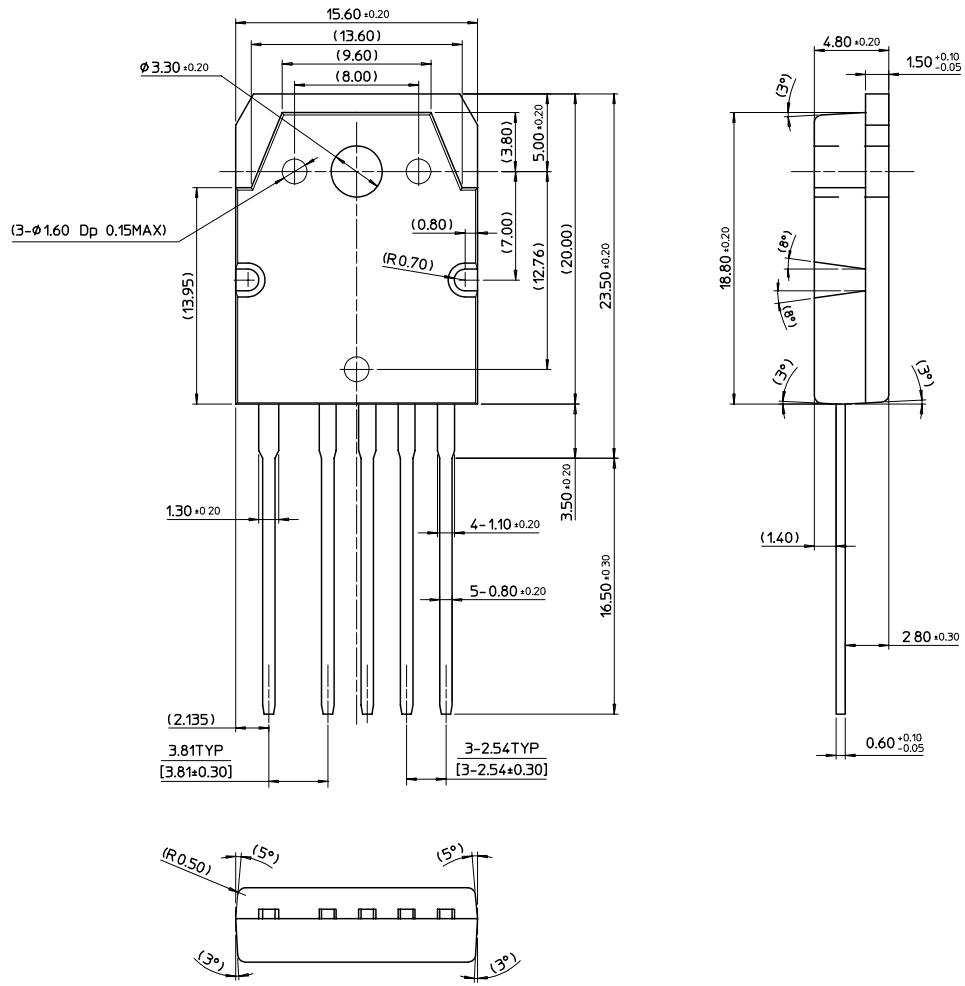
Package Dimensions (Continued)

TO-3P-5L (Forming)

Package Dimensions (Continued)

TO-3PF-5L

4.50 ±0.20

15.50 ±0.20

Ø 3.60 ±0.20

24.50 ±0.20

4.50 ±0.20

2.20 MAX

4-1.30 MAX

14.80 ±0.30

5-0.80 ±0.10

3.81TYP
[3.81±0.30]

3-2.54TYP
[3-2.54±0.30]

5.85 ±0.20

3.35 ±0.20

(1.65)

10.00 ±0.20

14.50 ±0.20

23.00 ±0.20

1.50 ±0.20

43.80 ±0.30

2.35 ±0.20

3.35 ±0.30

0.90 $^{+0.20}_{-0.10}$

3.35 ±0.20

2.35 ±0.20

5.85 ±0.20
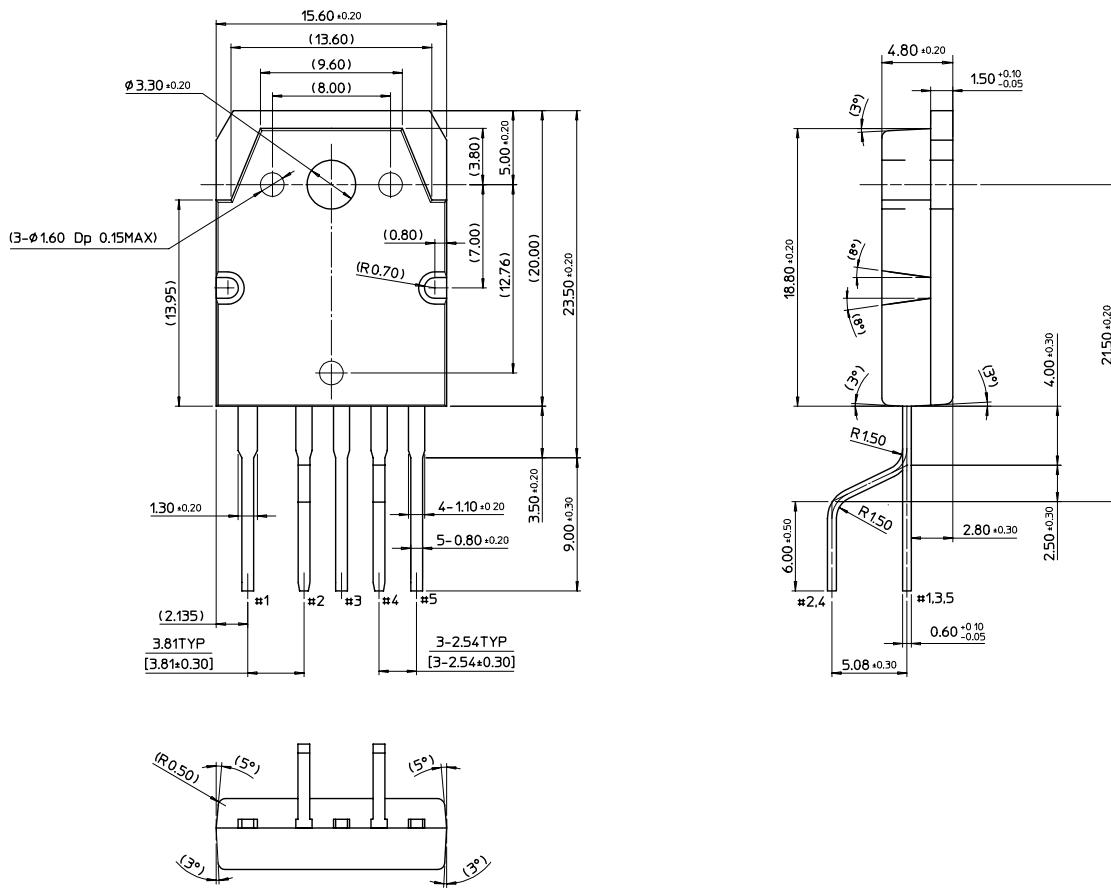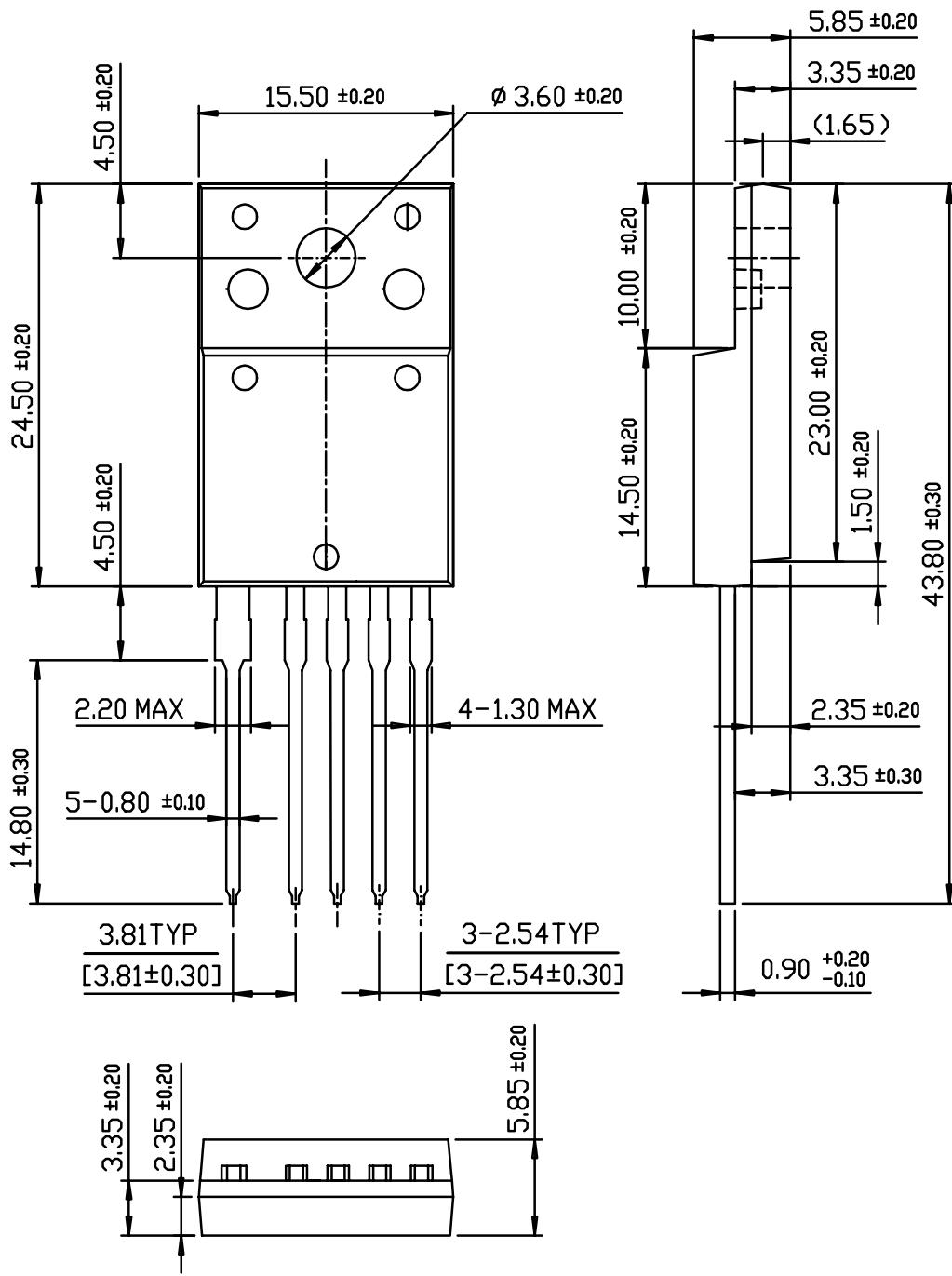
Package Dimensions (Continued)

TO-3PF-5L(Forming)
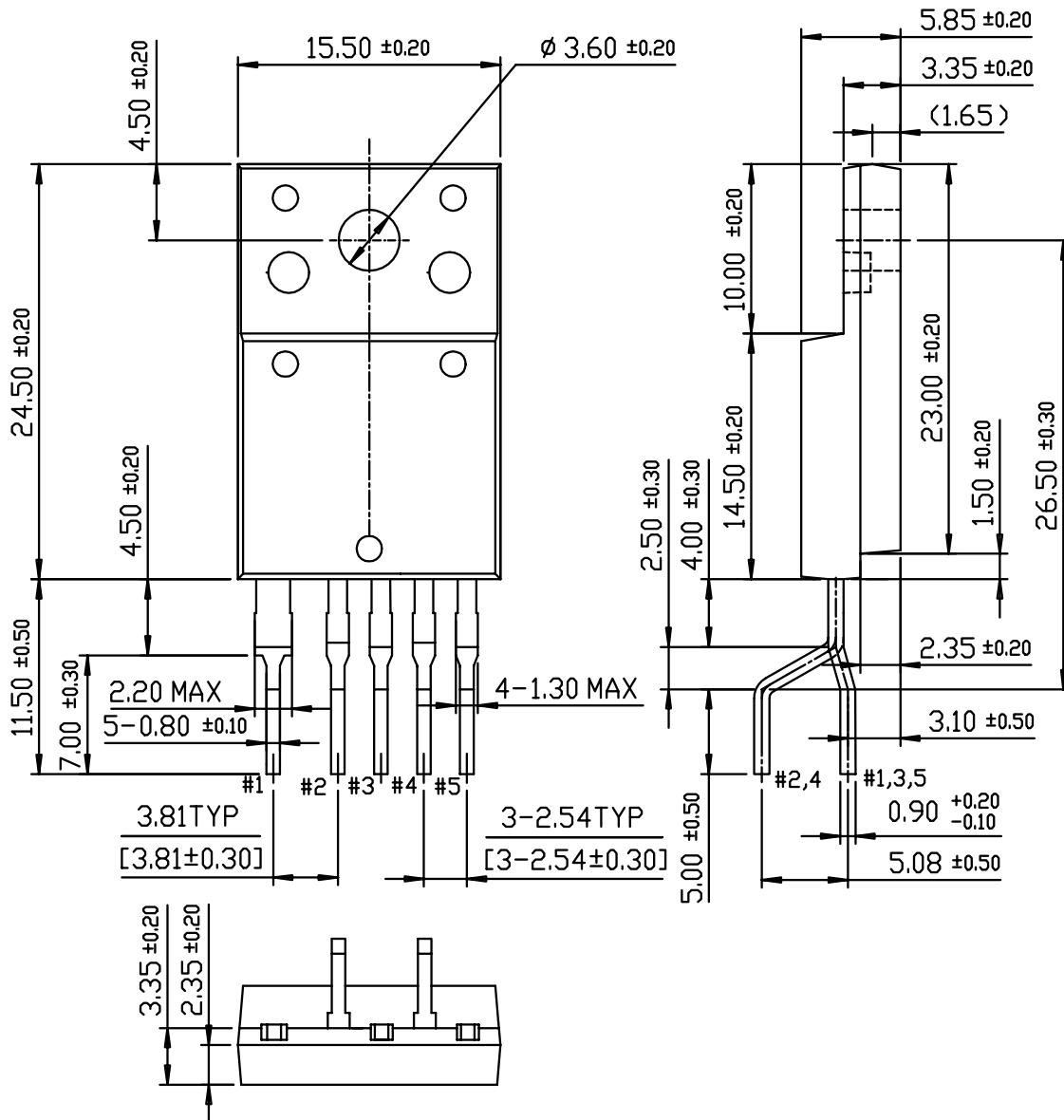
Ordering Information

Product Number	Package	Rating	Fosc	Latch/Auto
KA1M0680B-TU	TO-3P-5L	800V, 6A	67kHz	Latch up mode
KA1M0680B-YDTU	TO-3P-5L(Forming)			
KA1M0680RB-TU	TO-3P-5L	800V, 6A	67kHz	Auto restart mode
KA1M0680RB-YDTU	TO-3P-5L(Forming)			
KA1H0680B-TU	TO-3P-5L	800V, 6A	100kHz	Latch up mode
KA1H0680B-YDTU	TO-3P-5L(Forming)			
KA1H0680RFB-TU	TO-3PF-5L	800V, 6A	100kHz	Auto restart mode
KA1H0680RFB-YDTU	TO-3PF-5L(Forming)			

TU : Non Forming Type
YDTU : Forming Type

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